ULTRAFAST RECOVERY

1N5807US 1N5809US 1N5811US

April 20, 2000

TEL:805-498-2111 FAX:805-498-3804 WEB:http://www.semtech.com

SURFACE MOUNT HERMETICALLY SEALED ULTRAFAST RECTIFIER DIODE

Extremely low reverse recovery time

- Hermetically sealed to ensure reliable operation under most severe environmental and electrical stress
- Very low switching losses
- Soft, non-snap off, recovery characteristics
- Very low forward voltage drop

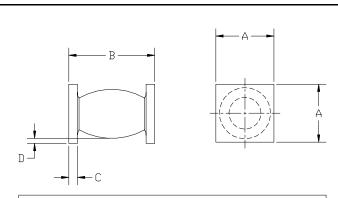
QUICK REFERENCE DATA

- V_R = 50 150V
- $I_F = 6.0A$
- trr = 30ns
- $I_R = 5\mu A$

ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

PARAMETER	SYMBOL	1N5807	1N5809	1N5811	UNITS
Working reverse voltage	V_{RWM}	50	100	150	V
Repetitive reverse voltage	V_{RRM}	50	100	150	V
Average forward current (@ 75°C, lead length = 0")	I _{F(AV)}		6.0	1	Α
Repetitive surge current (@ 55°C, in free air, lead length 0")	I _{FRM}	25			А
Non-repetitive surge current ($t_p = 8.3$ mS, @ $V_R \& T_{jmax}$)	I _{FSM}		125		Α
Operating temperature range	T _{OP}		-65 to +175		°C
Storage temperature range	T _{STG}		-65 to +200		°C

MECHANICAL OUTLINE



DIMENSIONS							
DIM	M	M	INCHES			IOTES	
	MIN	MAX	MIN	MAX			
Α	3.48	3.76	0.137	0.148			
В	5.08	5.72	0.200	0.225			
С	0.48	0.71	0.019	0.028			
D	0.80		0.003		DIM	PRE-SOLDER	

These products are qualified to MIL-S-19500/477 and are preferred parts as listed in MIL-STD-701.

They are available as JANTX, and JANTXV versions.





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ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	1N5807	1N5809	1N5811	UNITS
Maximum Average Forward Current	I _{F(AV)}	PCB mounted; T _A = 55°C for sine wave for square wave (d = 0.5)		А		
Maximum Average Forward Current	I _{F(AV)}	$T_L = 55^{\circ}C; L = 0$ " for sine wave for square wave		А		
Maximum I ² t for Fusing	l ² t	t = 8.3mS, sine wave		A ² S		
Maximum Forward Voltage Drop	V _F	$I_F = 4.0A, T_j = 25^{\circ}C$	0.875			V
Maximum Reverse Current	I _R	V_{RWM} , $T_j = 25$ °C		5.0		μA
		V_{RWM} , $T_j = 100$ °C		150		μA
Maximum Reverse Recovery Time	trr	$I_F = 1.0A$ to $I_{RRM} = 1.0A$ Recovers to $I_{RR} = 0.1A$	30		nS	
Maximum Junction Capacitance	C _j	$V_R = -5V$, $f = 1MHz$	60		pF	

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS	1N5807	1N5809	1N5811	UNITS
Maximum Thermal Resistance Junction to Tab	$R_{\theta jt}$			10		°C/W



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ELECTRICAL CHARACTERISTICS CURVES

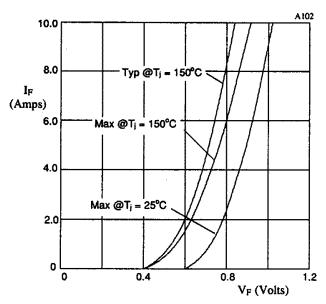


Fig 1. Forward voltage drop as a function of forward current.

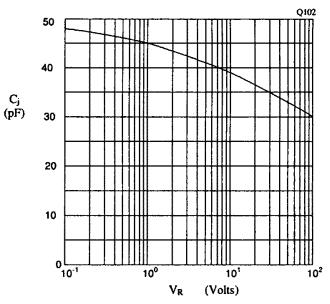


Fig 2. Typical junction capacitance as a function of reverse voltage.